# NSN 5961-01-159-3336

Transistor - Page 1 of 1





View Online at https://aerobasegroup.com/nsn/5961-01-159-3336

# Inclosure Material:

Ceramic

# **Overall Length:**

Between 0.050 inches and 0.080 inches

# **Overall Diameter:**

Between 0.080 inches and 0.105 inches

# Internal Configuration:

Junction contact

### **Mounting Method:**

Press fit

### **Features Provided:**

Hermetically sealed case

### Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

60.0 collector to base voltage/static/emitter open and 30.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage, static, collector open

# Current Rating Per Characteristic:

300.00 milliamperes source cutoff current

# Power Rating Per Characteristic:

200.0 milliwatts small-signal input power, common-collector preset

# Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

### **Special Features:**

Yellow dot on red field top side; junction pattern arrangement: npn

### Terminal Type And Quantity:

3 ribbon

Shelf Life:

N/a

### Unit Of Measure:

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### Demilitarization:

No

### Fiig:

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